

LM3519 High Frequency Boost White LED Driver with High-Speed PWM Brightness Control

Check for Samples: [LM3519](#)

FEATURES

- Drives 2 to 4 LEDs at 20mA
- Up to 30kHz PWM Dimming Control Capability
- >80% Peak Efficiency
- Up to 8MHz Switching Frequency
- Small External Components: 1 μ H - 3.3 μ H(typ.2.2 μ H) Inductor and 1 μ F Output Capacitor
- True Shutdown Isolation
- Over-Voltage Protection

- Wide Input Voltage Range: 2.7V to 5.5V
- Small Footprint SOT-23 Package

APPLICATIONS

- LCD, White LED Backlighting on Mobile Phones
- Digital Still Cameras and PDAs
- General Purpose LED Lighting in Handheld Devices

DESCRIPTION

The LM3519 drives up to 4 white LEDs with constant current to provide LCD backlighting in handheld devices. The LED current is internally set to 20mA. The series connection allows the LED current to be identical for uniform brightness and minimizes the number of traces to the LEDs. Brightness control is achieved by applying a PWM signal on enable with frequencies up to 30kHz.

The LM3519 features a proprietary PFM regulation architecture with switching frequencies between 2MHz to 8MHz, minimizing inductor size.

Over-voltage protection circuitry and high frequency operation permit the use of low-cost small output capacitors. During shutdown, the output is disconnected from the input in order to avoid leakage current path through the LEDs to ground.

The LM3519 is available in a tiny 6-pin SOT-23 package.

Typical Application

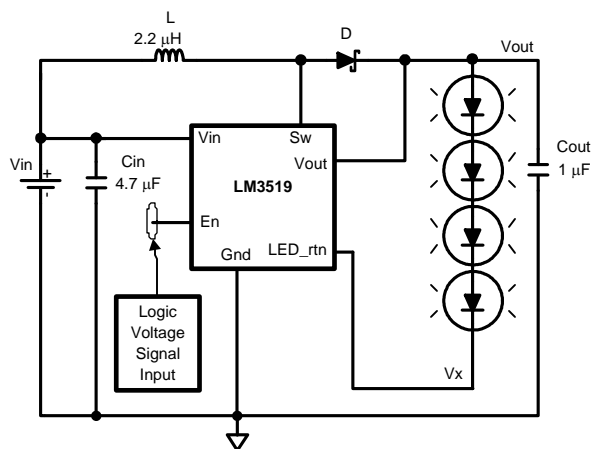


Figure 1. Typical Application Circuit

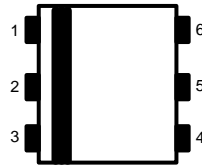


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Connection Diagram

6-Lead SOT-23 Package



Top View

PIN DESCRIPTIONS

Pin #	Name	Description
1	En	Device Enable Connection
2	Gnd	Ground Connection
3	V _{OUT}	Output Voltage Connection
4	LED_rtn	White LED Current Sensing Input Connection
5	S _W	Drain Connection of the Internal Power Field Effect Transistor (FET) Switch
6	V _{IN}	Input or Supply Voltage Connection



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings⁽¹⁾

V _{IN} , En, & LED_rtn Pin	-0.3V to +6.5V
V _{OUT} , Sw Pin	-0.3V to +21V
Maximum Junction Temperature, (T _{J-MAX})	+150°C
Storage Temperature Range	-65°C to +150°C
ESD Rating ⁽²⁾	
Human Body Model:	2kV
Machine Model:	200V

- (1) [Absolute maximum ratings](#) indicate limits beyond which damage to the device may occur. [Operating Ratings](#) are conditions under which operation of the device is guaranteed. Operating Ratings do not imply guaranteed limits. For guaranteed performance limits and associated test conditions, see the [Electrical Characteristics](#) table.
- (2) The human body model is a 100pF capacitor discharged through a 1.5kΩ resistor into each pin. The machine model is a 200pF capacitor discharged directly into each pin.

Operating Ratings⁽¹⁾

Junction Temperature (T _J) Range	-40°C to +125°C
Ambient Temperature (T _A) Range	-40°C to +85°C
Input Voltage Range	2.7V to 5.5V

- (1) [Absolute maximum ratings](#) indicate limits beyond which damage to the device may occur. [Operating Ratings](#) are conditions under which operation of the device is guaranteed. Operating Ratings do not imply guaranteed limits. For guaranteed performance limits and associated test conditions, see the [Electrical Characteristics](#) table.

Thermal Properties⁽¹⁾

Junction-to-Ambient Thermal Resistance (θ _{JA})	220°C/W
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- (1) The maximum allowable power dissipation is a function of the maximum junction temperature, T_{J(MAX)}, the junction-to-ambient thermal resistance, θ_{JA}, and the ambient temperature, T_A. See [Thermal Properties](#) for the thermal resistance. The maximum allowable power dissipation at any ambient temperature is calculated using: P_{D(MAX)} = (T_{J(MAX)} – T_A)/θ_{JA}. Exceeding the maximum allowable power dissipation will cause excessive die temperature.

Electrical Characteristics ⁽¹⁾⁽²⁾

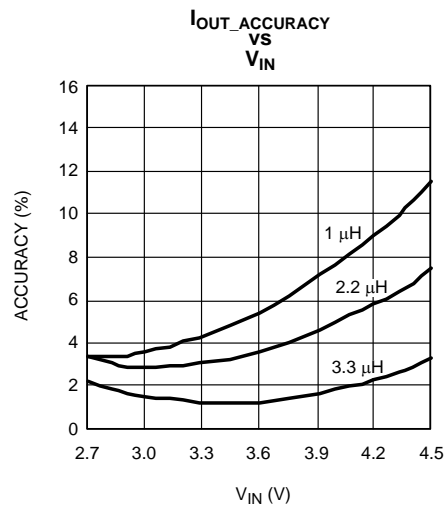
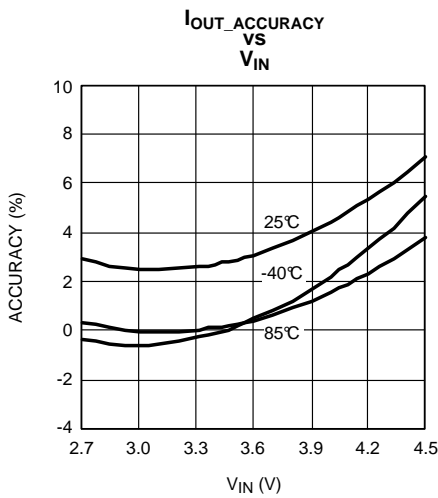
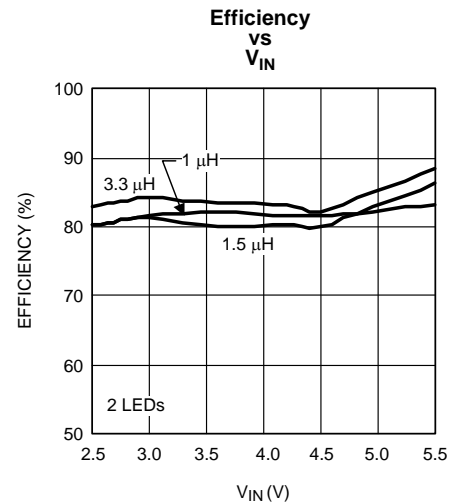
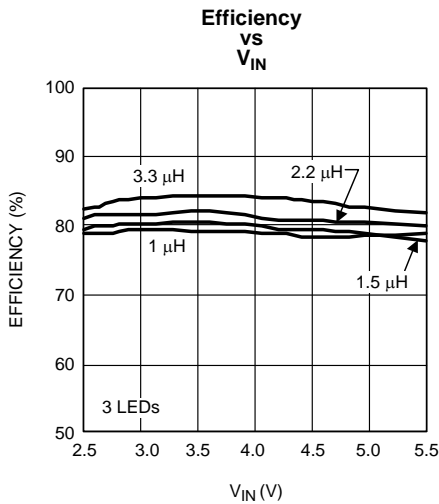
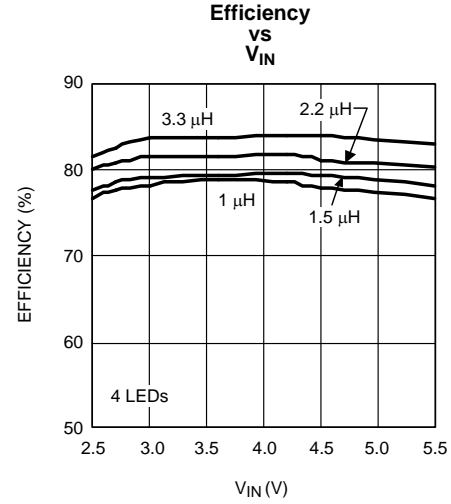
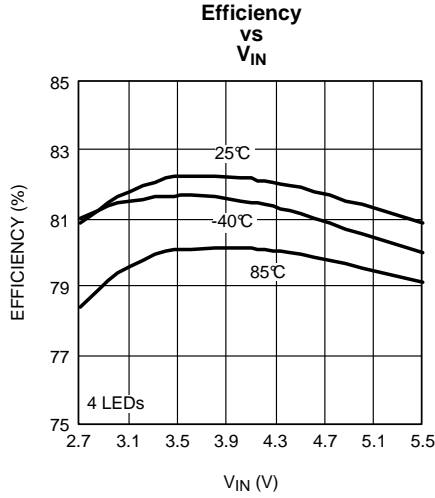
Limits in standard typeface are for $T_J = +25^{\circ}\text{C}$. Limits in **bold typeface** apply over the full operating junction temperature range ($-40^{\circ}\text{C} \leq T_J \leq +125^{\circ}\text{C}$). $V_{IN} = 3.6\text{V}$, unless otherwise stated.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
I_Q	Supply Current	Shutdown: $V_{EN} = 0\text{V}$		0.1		μA
		Not Switching: $V_{EN} = 1.8\text{V}$		360	500	
		Switching: $V_{EN} = 1.8\text{V}$, LED_rtn current = 30mA		550	900	
$I_{LED(TOL)}$	LED Current Tolerance/Variation	$V_{IN} = 3.6\text{V}$, 2.2 μH , 4LEDs	-10	5.5	10	%
OVP	Over-Voltage Protection Threshold	OVP ON OVP OFF	18 17.8	18.9 18.6	20 19.8	V
I_{LIM}	Switch Current Limit	$L = 2.2\mu\text{H}$		750		mA
$R_{DS(ON)}$	Power NMOS Switch ON Resistance			455		m Ω
$I_{LEAKAGE}$	Switch Leakage	$V_{SW} = 3.6\text{V}$, $V_{EN} = 0\text{V}$		0.1	2	μA
$R_{LED_rtn(ON)}$	LED_rtn NMOS Switch ON Resistance			8.0		Ω
F_S	Switching Frequency	$I_{LED} = 20\text{ mA}$, $L = 1\mu\text{H}$ 4LEDs		5.4		MHz
I_{EN}	Enable Pin Bias Current ⁽³⁾	$V_{EN} = 0\text{V}$ $V_{EN} = 1.8\text{V}$		0.1 1.1	2	μA
En	Enable Threshold	Device On Device Off	0.9		0.3	V

- (1) [Absolute maximum ratings](#) indicate limits beyond which damage to the device may occur. [Operating Ratings](#) are conditions under which operation of the device is guaranteed. Operating Ratings do not imply guaranteed limits. For guaranteed performance limits and associated test conditions, see the [Electrical Characteristics](#) table.
- (2) Min and max limits are guaranteed by design, test, or statistical analysis. Typical numbers are not guaranteed, but do represent the most likely norm.
- (3) Current flows into the pin.

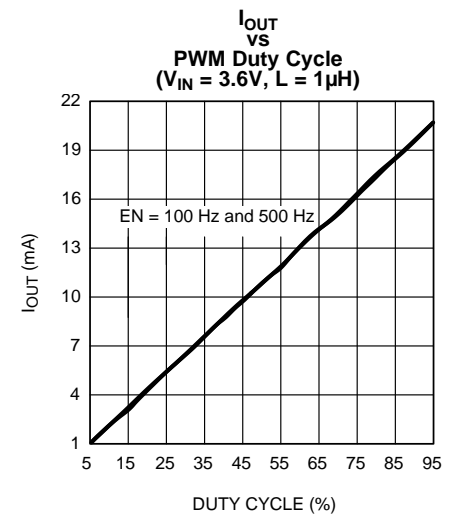
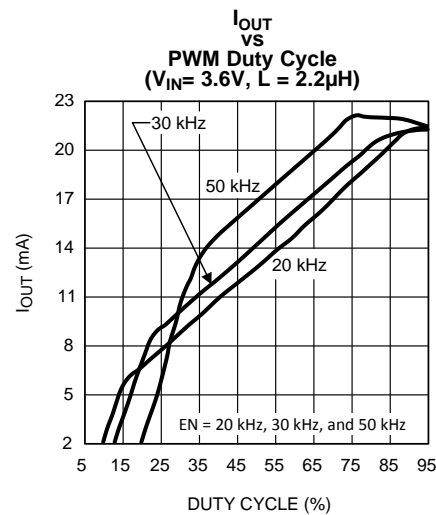
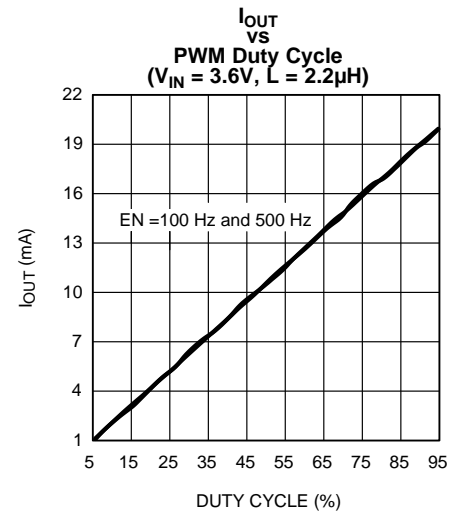
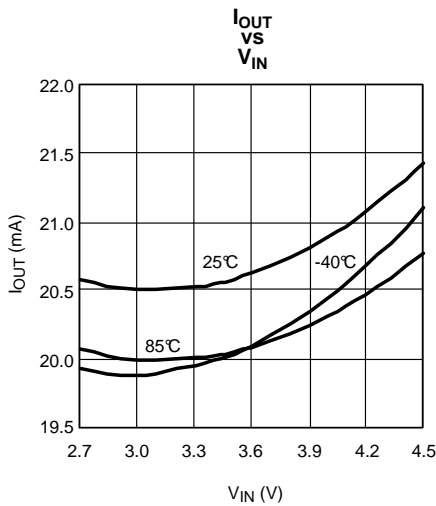
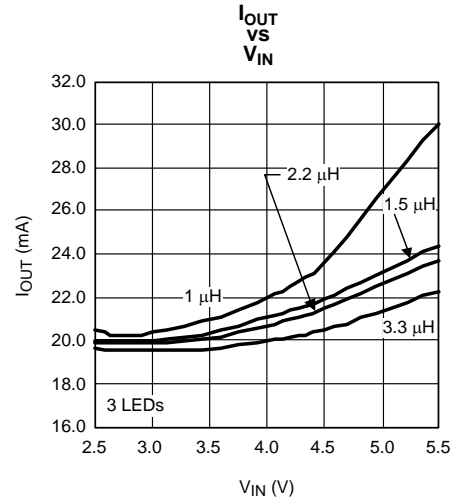
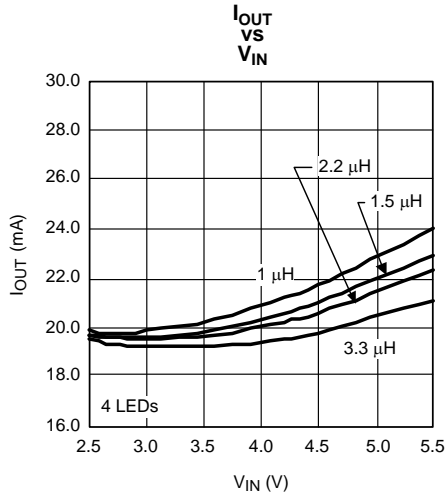
Typical Performance Characteristics

(See Figure 1: $V_{IN} = 3.6V$, $C_{IN} = 4.7\mu F$ and $C_{OUT} = 1\mu F$, $L = 2.2\mu H$ and 4 LEDs. $T_A = +25^\circ C$, unless otherwise stated.)



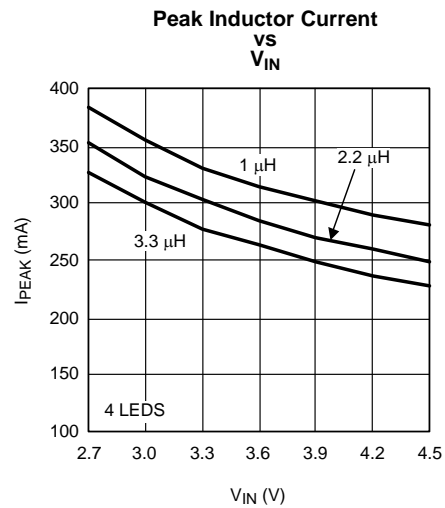
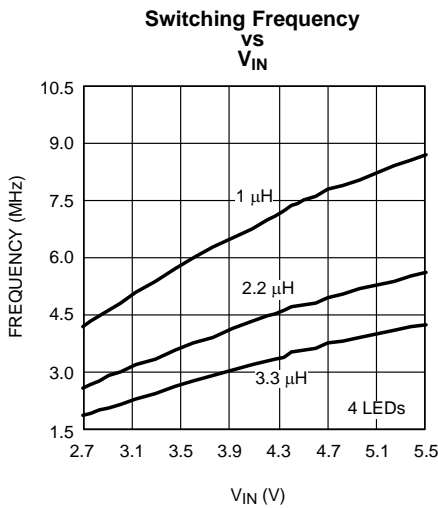
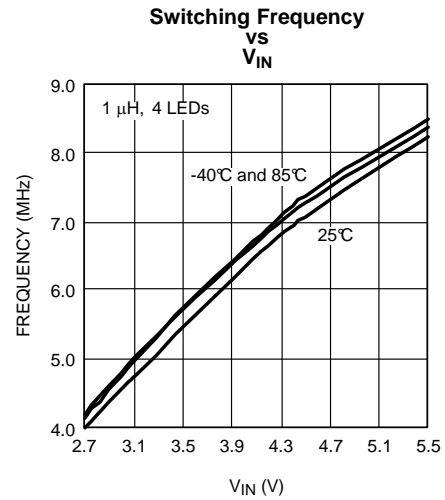
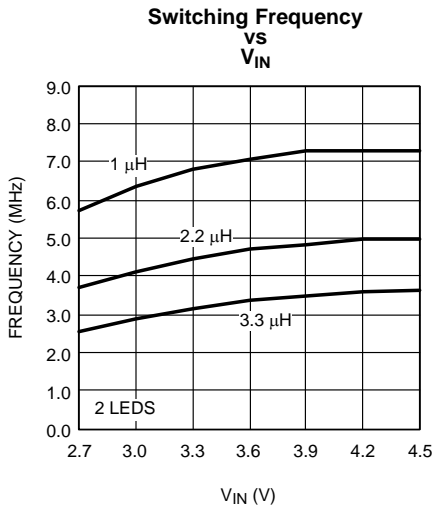
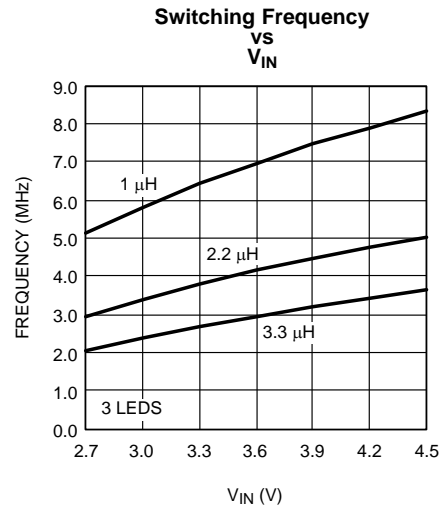
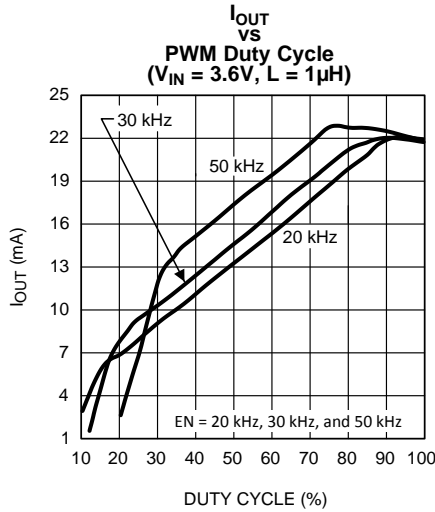
Typical Performance Characteristics (continued)

(See Figure 1: $V_{IN} = 3.6V$, $C_{IN} = 4.7\mu F$ and $C_{OUT} = 1\mu F$, $L = 2.2\mu H$ and 4 LEDs. $T_A = +25^\circ C$, unless otherwise stated.)



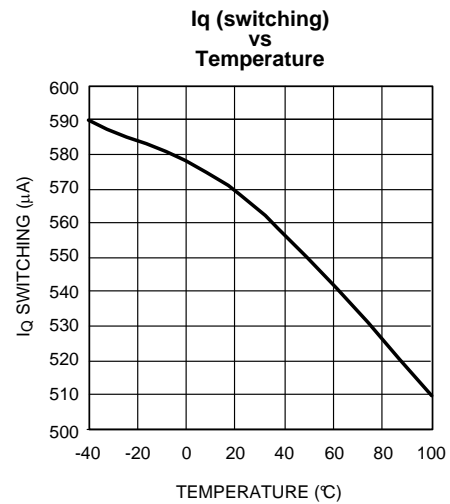
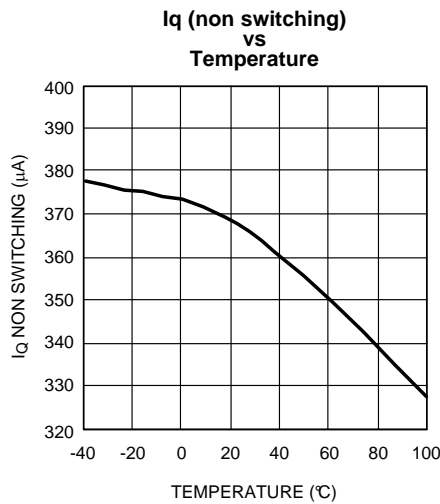
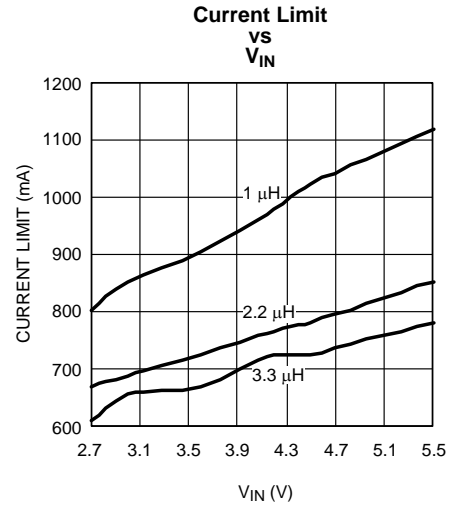
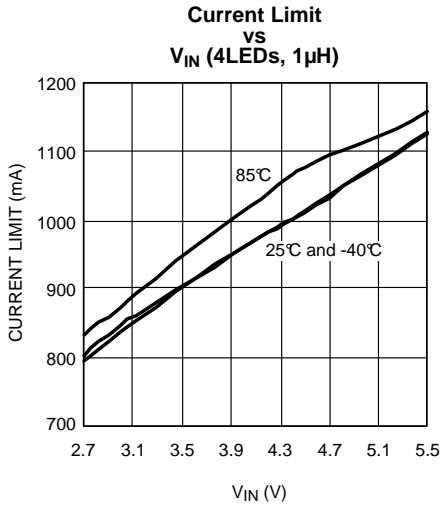
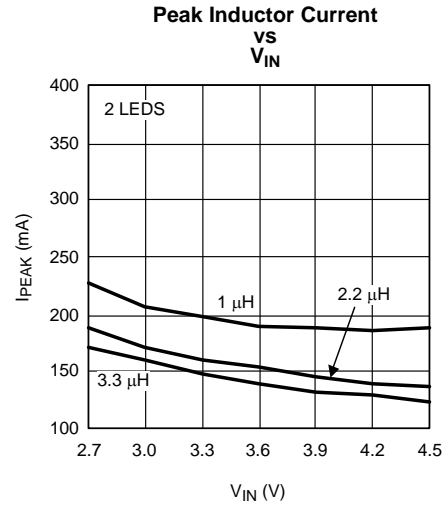
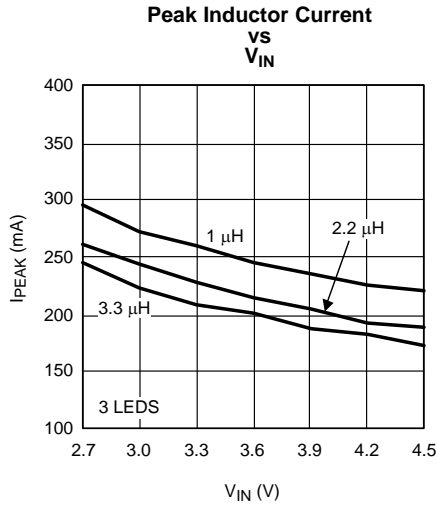
Typical Performance Characteristics (continued)

(See Figure 1: $V_{IN} = 3.6V$, $C_{IN} = 4.7\mu F$ and $C_{OUT} = 1\mu F$, $L = 2.2\mu H$ and 4 LEDs. $T_A = +25^\circ C$, unless otherwise stated.)



Typical Performance Characteristics (continued)

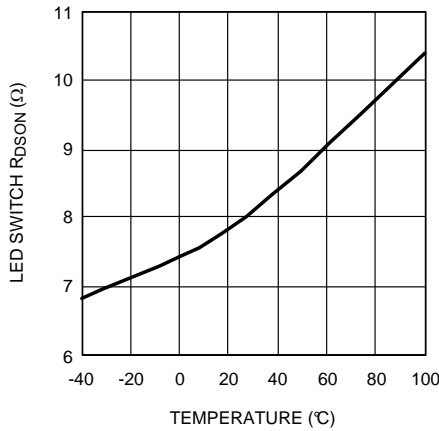
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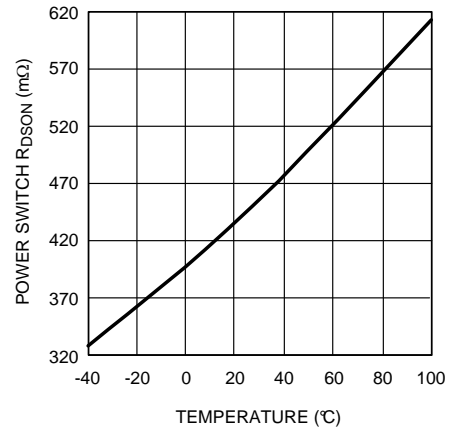
Typical Performance Characteristics (continued)

(See Figure 1: $V_{IN} = 3.6V$, $C_{IN} = 4.7\mu F$ and $C_{OUT} = 1\mu F$, $L = 2.2\mu H$ and 4 LEDs. $T_A = +25^\circ C$, unless otherwise stated.)

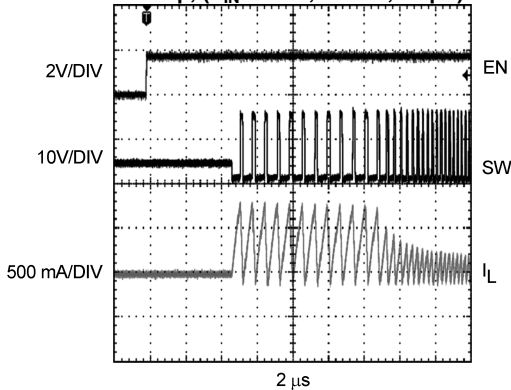
**LED Switch R_{DS_ON}
VS
Temperature**



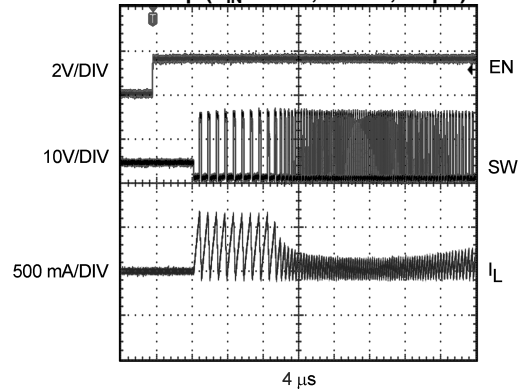
**Power Switch R_{DS_ON}
VS
Temperature**



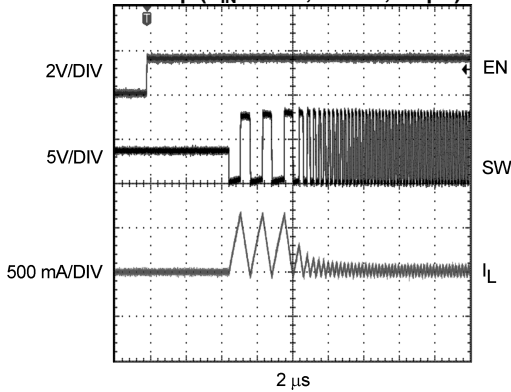
Start-up, ($V_{IN} = 3.6V$, 4LEDs, 2.2 μH)



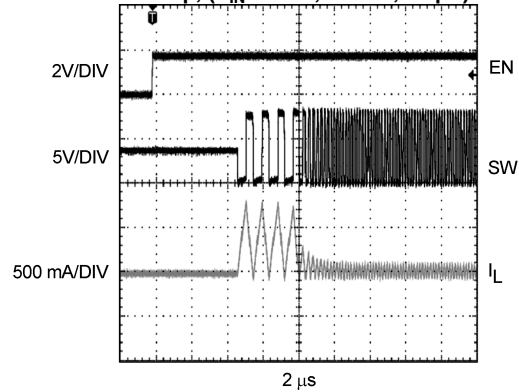
Start-up ($V_{IN} = 3.6V$, 4LEDs, 3.3 μH)



Start-up ($V_{IN} = 3.6V$, 2LEDs, 3.3 μH)

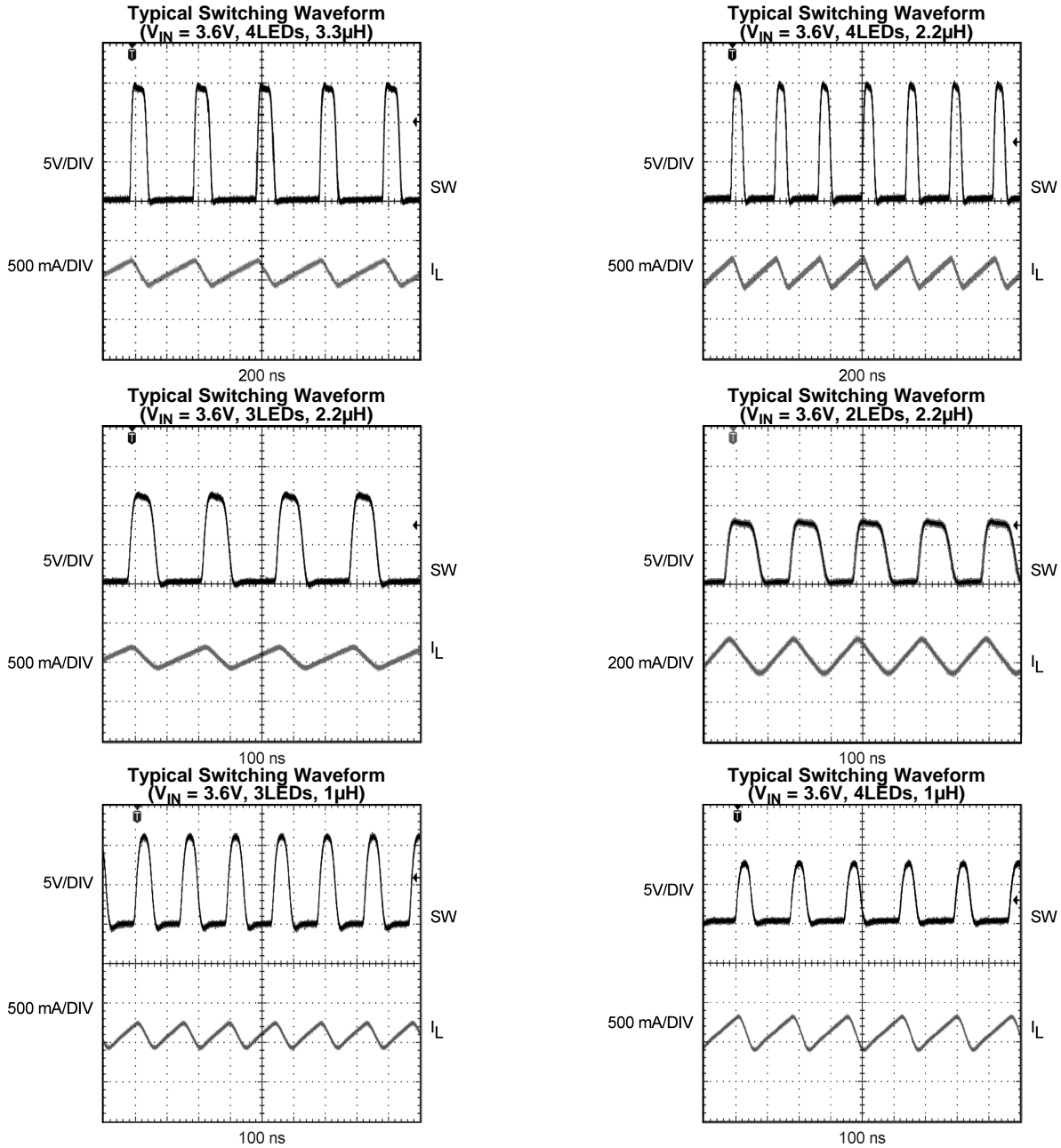


Start-up, ($V_{IN} = 3.6V$, 2LEDs, 2.2 μH)



Typical Performance Characteristics (continued)

(See Figure 1: $V_{IN} = 3.6V$, $C_{IN} = 4.7\mu F$ and $C_{OUT} = 1\mu F$, $L = 2.2\mu H$ and 4 LEDs. $T_A = +25^\circ C$, unless otherwise stated.)



APPLICATION INFORMATION

Capacitor Selection

To minimize output and input voltage ripple, low equivalent series resistance (ESR) ceramic capacitors are the best choice to use for the input and output filters. For most display applications, a 4.7 μ F capacitor is recommended for C_{IN} and 1 μ F for C_{OUT} .

Larger output capacitors can be used to reduce ripple voltage. To guarantee good performance, a minimum of 0.47 μ F C_{OUT} is required to trade off for large ripple voltage. Care must be taken to account for the true capacitance of a multilayer ceramic capacitor. Smaller case size capacitors typically have less capacitance for a given bias voltage as compared to a larger case size capacitor with the same bias voltage. Please confirm with capacitor manufacturer data before selecting the capacitor.

Recommended capacitor manufacturers include but are not limited to:

Table 1.

Manufacturer	Description	Case Size
AVX	06033D105MAT-25V	0603
	06036D475MAT-6.3V	0603
TDK	C2012X5R1A475M-10V	0805
Taiyo Yuden	TMK212BJ105KG-J	0805
	EM212BJ475MG-16V	0805
muRata	GRM40-034B105K25	0805
	GRM39X5R475K6.3	0603

Inductor Selection

In order to maintain sufficient inductance, the saturation current rating of the inductor used with the LM3519 should be higher than the peak inductor current in the target application. Inductors with low DCR values have less power loss and higher efficiency. Larger inductor values such as 2.2 μ H and 3.3 μ H can be used to optimize efficiency, frequency and peak current. If 1 μ H is used, the peak inductor current, frequency will be higher and the efficiency will be lower. Note that the switching frequency ranges will be higher at lower inductance. Typical frequency range is between 4 to 8MHz for 1 μ H, 2 to 5MHz for 2.2 μ H and 2 to 4MHz for 3.3 μ H over the input range. Below is a sample list of low profile inductors.

Some recommended inductor manufacturers include but are not limited to:

Manufacturer	L	Case Size	I _{SAT}
CoilCraft: DO3314-102	1 μ H	3.3x3.3x1.4mm	2.1A
	2.2 μ H		1.6A
	3.3 μ H		1.4A
Coilcraft: LPO3310-102ML	1 μ H	3.3x3.3x1.0 mm	1.6A
	2.2 μ H		1.1A
	3.3 μ H		0.95A
Cooper: SD31121R0	1 μ H	3.1x3.1x1.4 mm	2.07A
	2.2 μ H		1.48A
	3.3 μ H		1.15A
Taiyo Yuden: NR3015T1R0N	1 μ H	3.0x3.0x1.5 mm	2.1A
	2.2 μ H		1.48A
	3.3 μ H		1.21A

Diode Selection

Diodes with low forward voltage ratings (V_F) and low junction capacitance magnitudes (C_J or C_T or C_D) are conducive to high efficiency. The chosen diode must have a reverse breakdown voltage rating (V_R and/or V_{RRM}) that is larger than the output voltage. The following criteria should be followed when choosing a diode:

1. V_R (Diode Blocking Voltage Range) and V_{RRM} (Diode Peak Repetitive Reverse Voltage Rating) $> V_{OUT}$ (Output Voltage)
2. I_F or I_O (Diode Average Forward Current Rating) $\geq I_{LOAD}$ (Load Current)
3. I_{FRM} (Diode Peak Repetitive Forward Current Rating) $\geq I_{Lpeak}$ (Peak Inductor Current)

Some recommended diode manufacturers include but are not limited to:

Manufacturer	Description
Vishay	SS12(1A/20V)
	SS14(1A/40V)
	SS16(1A/60V)
Central Semiconductor	CMSH1- 40M(1A/40V)
ONSem	MBRS1540T3(1.5A/40V)

PWM DIMMING

The LED current is set internally by the LM3519 to 20mA (typical); dimming control may be realized by applying a pulse width modulated (PWM) signal to the En pin. For example, a 50% duty cycle waveform will produce an average current of 10mA. A control signal frequency between 17kHz and 30kHz is suitable for dimming.

Although the LM3519 is capable of operation outside this frequency range, it is not recommended to operate below 17kHz for the following reasons: 1) frequency below 100Hz is likely to cause visible flicker in the light emitted by the LED string, 2) frequency below 17kHz may induce audible noise due to combinations of some capacitance/PCB. A PWM frequency above 30kHz is possible but the current linearity vs duty cycle will be affected.

If it is not possible to operate the dimming control above 17kHz, audible noise emission may be minimized by using capacitors with low susceptibility to piezoelectric induced stresses, such as poly film designs. Minimum audible noise is most likely to occur when the PWM frequency is less than 2kHz. It is recommended that any application using a PWM control signal below 17kHz be thoroughly evaluated for undesirable audible or visible noise.

DRIVING 2 LEDs

The LM3519 is optimized to drive up to 4LEDs. When driving 2LEDs, a minimum inductance of 2.2 μ H is required to maintain good loop regulation and current accuracy. If a smaller inductor is used, the LED current will have more variation with input voltage than a typical application. The following curve illustrates the behavior.

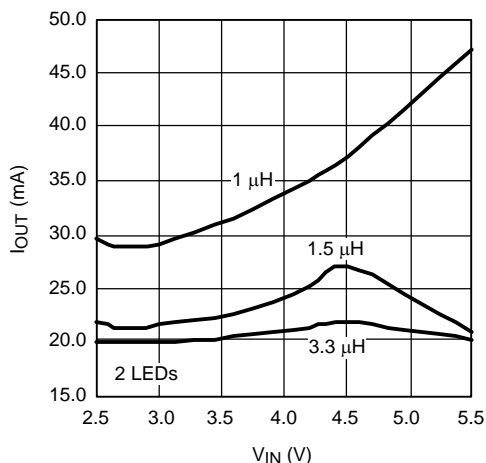


Figure 3. I_{OUT} vs V_{IN}

LAYOUT GUIDELINES

The input capacitor, C_{IN}, must be placed close to the LM3519. Placing C_{IN} close to the device will reduce the metal trace resistance effect on input voltage ripple. Metal trace connections for the C_{OUT} capacitor can increase the effective series resistance, which affects output voltage ripple and efficiency. Trace connections to the inductor should be short and wide to reduce power dissipation, increase overall efficiency and reduce EMI radiation. The diode, like the inductor, should have trace connections that are short and wide to reduce power dissipation and increase overall efficiency. For more details regarding layout guidelines for switching regulators, refer to Application Note AN1149.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LM3519MK-20	ACTIVE	SOT	DDC	6	1000	TBD	Call TI	Call TI	-40 to 85	D52B	Samples
LM3519MK-20/NOPB	ACTIVE	SOT	DDC	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	D52B	Samples
LM3519MKX-20	ACTIVE	SOT	DDC	6	3000	TBD	Call TI	Call TI	-40 to 85	D52B	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM3519MK-20	SOT	DDC	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3519MK-20/NOPB	SOT	DDC	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3519MKX-20	SOT	DDC	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

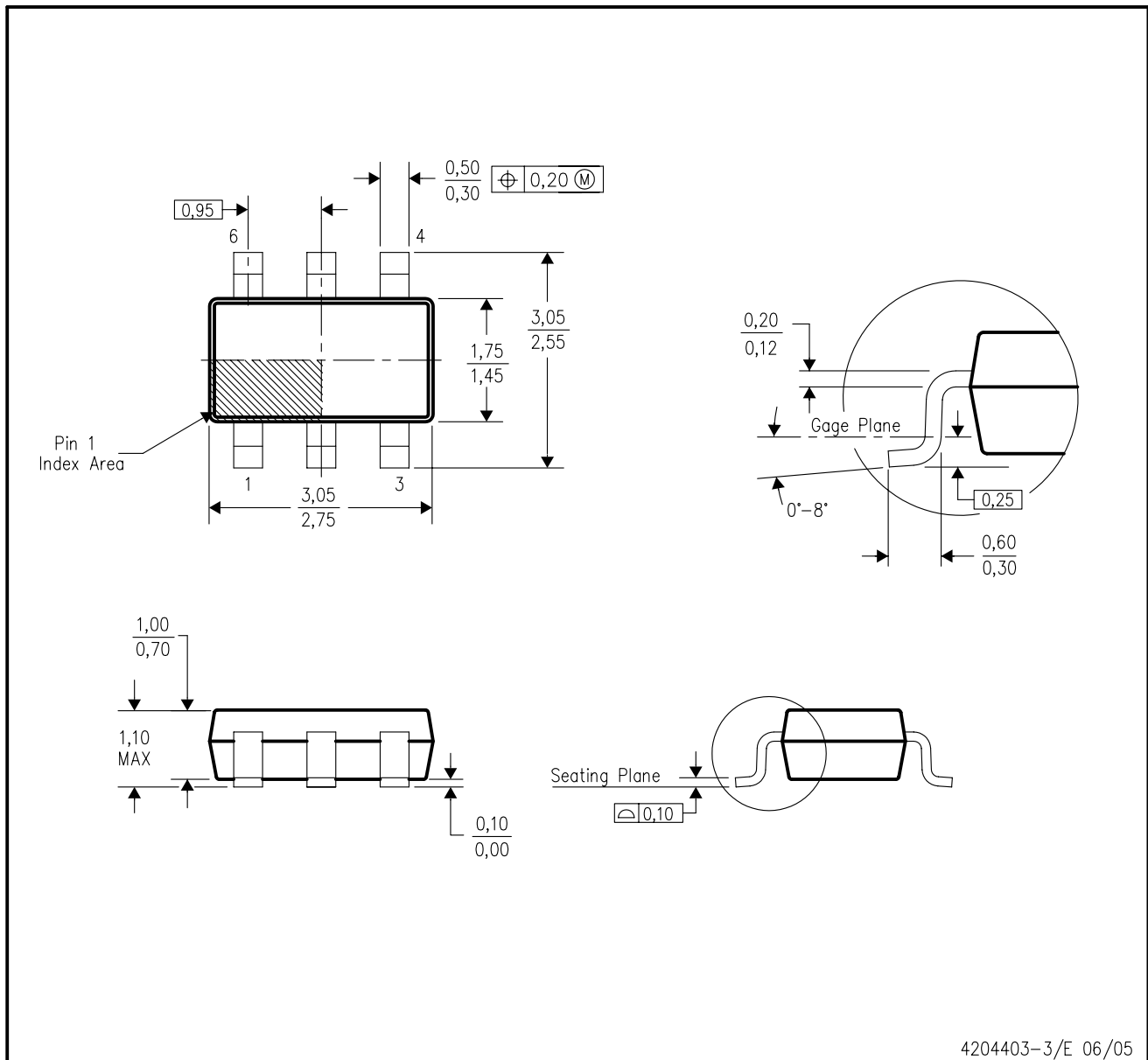
TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM3519MK-20	SOT	DDC	6	1000	203.0	190.0	41.0
LM3519MK-20/NOPB	SOT	DDC	6	1000	203.0	190.0	41.0
LM3519MKX-20	SOT	DDC	6	3000	206.0	191.0	90.0

DDC (R-PDSO-G6)

PLASTIC SMALL-OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion.
 - Falls within JEDEC MO-193 variation AA (6 pin).

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